OCXO3307C-42.8MHz-B-V

Ultra Low Power Miniature Low Profile OCXO

### Features and Benefits

Very Low Power Consumption: 0.15W at +25°C

TEL: 1-281-870-8822 EMAIL: Sales@DynamicEng.com

Fast Warming-up: 60 s typical

Low Aging: +/-3.0 ppb/day, +/-300 ppb/year

# Typical Applications

Portable Wireless Communications Mobile Test equipment Synthesizers Battery Powered Application

#### Description

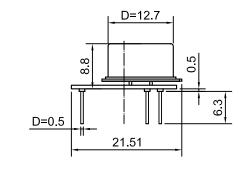
The OCXO3307C-42.8MHz-B-V utilizes the internal heating resonator (IHR) technology incorporating the whole oven system together with the crystal plate inside the TO-8 vacuum holder. Such an OCXO concept results in radical reduction of its volume, power consumption and warm-up time. In spite of the miniature sizes and extremely low power consumption such oscillators exhibit excellent temperature stability, low phase-noise and aging rate being at the level of high-end OCXOs using conventional oven designs.

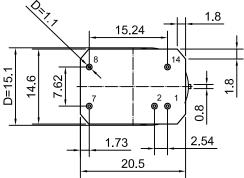
# Mechanical Drawing & Pin Connections

Drawing No:

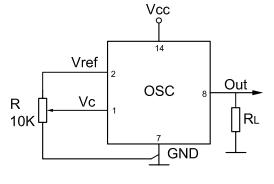
MD140076-1

#### Physical dimensions





## **Schematic connections**



Pin	Signal
1	Electrical tuning
2	Reference voltage
7	GND
8	RF Out
14	+V Supply

Unit: mm 1mm=0.0394inch



# Dynamic Engineers Inc.

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# **Specifications**

Oscillator Specification		Com	Condition	Value			Heit	N. d			
		Sym	Condition	Min.	Тур.	Max.	Unit	Note			
Operational Frequency		F <sub>nom</sub>			42.800000		MHz				
Initial tolerance			at +25°C, Vc=Vc0	-0.2		+0.2	ppm				
RF Output											
Waveform :					HCMOS						
Load					10K//10pF		K//pF				
H-level voltage				3.8			V				
L-level voltage						0.4	V				
Duty cycle				45		55	%				
Rise/Fall time						10	ns				
Sub-harmonics level					none						
Frequency con	trol										
Control voltage range		V <sub>c</sub>		0		4.2	V				
Frequency Turn	ing Range			+/-0.5	+/-1	-	ppm	+			
Reference Voltage		$V_{ref}$		4.1	4.2	4.3	V				
Power Supply											
Voltage		V <sub>cc</sub>		4.75	5.0	5.25	V				
Power consumption			Warm-up state		0.7		W				
			@ +25°C steady state		0.15		1				
Warm-up Time:		$T_{up}$	to $\Delta f/f = 1e^{-7}$ at +25°C		60		s	ref. to frequencyafter 15 min			
Frequency Stal											
Vs.Temperature			Ref. 25°C			+/- 10	ppb				
Vs. Supply Voltage			Ref Vcc typ.		+/-2		ppb				
vs. direction			worst direction			+/-1	ppb/g				
Aging	per day		after 30days of operation			+/-3	ppb				
	first year		,			+/-300	ppb				
SSB Phase noise			1 Hz		-75						
			10 Hz		-105						
			100 Hz		-125		dBc/Hz				
			1 KHz		-145						
			10KHz		-155						
	Environmental Conditions		100 KHz		-160						
		20001 20	200								
Storage temperature range			-60°C to 90°C								
Operating temperature range		-40°C to 85°C									
Humidity Mechanical Shock		Non-condensing 95%									
	ICK	MIL-STD-202, 30G half sine pulse, 11 ms									
Vibration Washing Condit	iono	MIL-STD-202, 5G swept sine, 10 to 2000 Hz Washing with water or alcohol based detergent allowed only with final enough drying stage									
		Wasning v	or only not reflow compatible	260°C 40°	veu only with tir	iai eriough (	arying stage				
Soldering Condi	Soldering Conditions Hand solder only – not reflow compatible 260°C 10s(on pins)										